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最新トランジスタ規格表 (New Transistor Manual) lists all the transistors registered with the Electronic Industries Association of Japan (EIAJ), arranged in a manner easy to look up. We hope that you will make full use of the data provided in this manual by referring to the Japanese-English translation key given below.

型名	社名	用途	構造	最大定格 (T _b =25°C)					電気的特性 (T _b =25°C)										備考	
				V _{ceo} (V)	V _{ceo} (V)	I _c (mA)	P _c (mW)	T _j (°C)	I _{ceo} 最大値 (μA)	直流又はパルスI _{BE}		バイアス		h _{FE}	h _{FE} h _{FE} * (Ω)	h _{FE} h _{FE} * (×10 ⁻⁴)	h _{FE} h _{FE} * (μS)	f _{αB} f _r * (Mc)		C _{ob} (pF)
1	2	3	4	5					6		7		8				9	10	11	12

- 1 TYPE NUMBER
- 2 ORIGINAL MANUFACTURER
- 3 USES
- 4 MATERIAL AND STRUCTURE
- 5 MAXIMUM RATINGS
- 6 I_{CBO} MAXIMUM VALUE AND V_{CB} VALUE (CRITERIA FOR MEASURING I_{CBO})
- 7 STANDARD VALUE OF DC/PULSE h_{FE} AND V_{CE}, I_C (CRITERIA FOR MEASURING DC/PULSE h_{FE})
- 8 STANDARD VALUE OF h PARAMETERS AND BIAS V_{CB}, I_E (CRITERIA FOR MEASURING h PARAMETERS)

- * INDICATES VALUE IN GROUNDED-BASE OPERATION, OTHERWISE VALUE IN EMITTER-GROUNDED OPERATION.
 - 9 f_{αB} OF RF CHARACTERISTIC, EXCEPT IN CASE OF * WHICH INDICATES VALUE OF f_r.
 - 10 C_{ob} AND r_{bb'} OF RF CHARACTERISTICS EXCEPT IN CASE OF * IN r_{bb'} COLUMN WHICH INDICATES VALUE OF h_{ie} (real)
 - 11 OUTLINE
 - 12 REMARKS
- :とコンプリ: COMPLEMENTARY TO

型名	社名	用途	構造	最大定格 (T _a = 25°C)							電 気 的 特 性 (T _a = 25°C)											外 形	備 考	
				V _{CB0} (V)	V _{EBO} (V)	I _c (mA)	P _c (mW)	T _j (°C)	I _{CBO} 最大値		直 流 又 は バ ル ス h _{FE}			バ イ ア ス		h _{fe} h _{fs} *	h _{ie} h _{is} * (Ω)	h _{re} h _{rs} * (×10 ⁻⁴)	h _{oe} h _{os} * (μΩ)	f _{βB} f _T * (Mc)	C _{ob} (pF)			r _{βB} h _{ie} (real)* (Ω)
									(μA)	V _{CB} (V)	V _{CE} (V)	I _C (mA)	V _{CB} (V)	I _E (mA)										
2SC362	東 芝	RF.Conv.Mix Osc	Si.P	25	5	100	200	125	0.5	18	70~280	12	2	6	-2	140			150*	4	90	33		
" 363	"	"	"	25	5	100	200	125	0.5	18	150~500	12	2	6	-2	250			150*	4	90	33		
" 364	"	RF.Conv Mix.Osc	"	25	5	40	200	125	0.5	18				6	-2	400			150*	4	100	33		
" 365	"	"	"																					
" 366	東 芝	RF.Conv Mix.Osc	Si.E	60	5	400	400	125	0.1	40	70~240	1	100	10	-10	60			>100*	10	50	138		
* " 367	"	"	"	40	5	400	400	125	0.1	40	70~240	1	100	10	-10	70			>100*	10	50	138	2SA467 ヒコンプリア	
* " 368	"	RF.Conv.Mix Osc	"	25	5	100	250	175	0.1	18				10	-1	250			150*	1.5	120	49C		
* " 369	"	"	"	18	5	100	200	125	0.1	18				10	-1	250			150*	1.5	120	33		
* " 370	"	"	"	30	4	100	200	125	1	18				6	-1	40			150*	2.5	80	33		
* " 371	"	"	"	30	4	100	200	125	1	18				6	-1	80			150*	2.5	80	33		
* " 372	"	"	"	60	5	150	400	125	0.1	60	70~400	1	10	10	-1				200*	2	50	138	2SA495 ヒコンプリア	
* " 373	"	"	"	60	5	150	400	125	0.1	60	200~400	1	10	10	-1				200*	2	50	138		
* " 374	"	"	Si.EP	30	4	100	200	125	1	18				6	-1	400			150*	2.5	80	33		
* " 375	"	RF	"	20	2	50	200	125	0.5	15				10	-8	100			600*	1.5	20	33		
* " 376	"	"	"	70	4	100	200	125	1	18				6	-1	60			150*	2.5	40	33		
* " 377	"	"	"	35	4	30	200	125	0.5	18				12	-2	70			150*	2	C _c r _{βB} 40pS	33		
* " 378	"	RF.Conv.Mix	"	35	4	30	200	125	0.5	18	40~240	12	2	10	-1				150*	2	C _c r _{βB} 40pS	33		
* " 379	"	RF.Conv.Mix Osc	"	30	4	100	200	125	0.5	18				10	-2	70			300*	2	40	33		
* " 380	"	RF	"	35	4	50	300	125	0.1	35	40~240	12	2	10	-1				100~400	2	C _c r _{βB} 10~50pS	138		
* " 381	"	"	"	40	4	20	100	125	0.5	18	25~140	6	1	6	-1				250*	2	C _c r _{βB} 10pS	33		
* " 382	"	"	Si.P	40	4	50	250	125	0.1	40	>30	10	4	10	-4		PG > 32 dB (f = 45Mc)		>400*	C _c r _{βB} <1.2	C _c r _{βB} <30pS	138	フイワー A.G.C	
* " 383	"	"	Si.EP	50	4	50	300	125	0.1	50	20~100	12.5	12.5	12.5	-12.5				>300*	0.8~ 2.0		138		
* " 384	"	RF.Conv. Mix.Osc	"	20	2	50	200	125	0.5	15				6	-1	50			500*	1.4	25	33		
* " 385	"	"	"	20	2	20	200	125	0.5	15				3	-8	80			600*	1.6	20	33		
* " 386	"	RF.Conv. Mix	"	20	2	20	200	125	0.5	15				3	-8	80			500*	1.6	18	33		
* " 387	"	RF.Conv.Mix Osc	"	20	2	50	200	125	0.5	15				10	-8	100	P _s = 8mW (f = 930Mc)		900*	1.4	15	33		
* " 388	"	RF.Conv. Mix	"	20	2	20	200	125	0.5	15				3	-8	80			450*	1.6	18	33		
* " 389	"	RF	Si.P	20	3	20	150	150	0.1	10				5	-4	50			500*	0.8	10	50C		
" 390	"	"	Si.EP	30	3	20	150	150	0.1	10	40~200	10	2	10	-2		NF = 2 dB (f = 100Mc, 10V, 2mA)		1000*	0.1	C _c r _{βB} < 6 pS	50C		
* " 391	"	"	"	20	2	20	150	150	1	10				10	-2	70			1200*	1	C _c r _{βB} 5 pS	50C		